

HSM223C

Silicon Epitaxial Planar Diode for High Speed Switching

REJ03G0553-0500 (Previous: ADE-208-092D) Rev.5.00 Mar 10, 2005

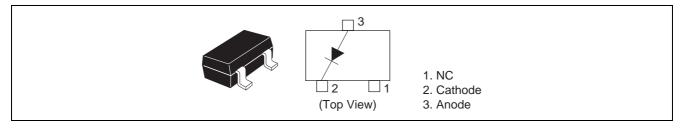
## Features

- Low capacitance, proof against high voltage.
- Fast recovery time.
- MPAK package is suitable for high density surface mounting and high speed assembly.

# **Ordering Information**

Type No.	Laser Mark	Package Name	Package Code (Previous Code)
HSM223C	A8	MPAK	PLSP0003ZC-A (MPAK)

# **Pin Arrangement**





# **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
Item	Symbol	Value	Unit
Peak reverse voltage	V <sub>RM</sub>	85	V
Reverse voltage	V <sub>R</sub>	80	V
Peak forward current	I <sub>FM</sub>	300	mA
Non-Repetitive peak forward surge current	I <sub>FSM</sub> * <sup>1</sup>	4	А
Average rectified current	lo	100	mA
Junction temperature	Тј	125	°C
Storage temperature	Tstg	-55 to +125	٥°

Note: 1. Value at duration of 1  $\mu$ s.

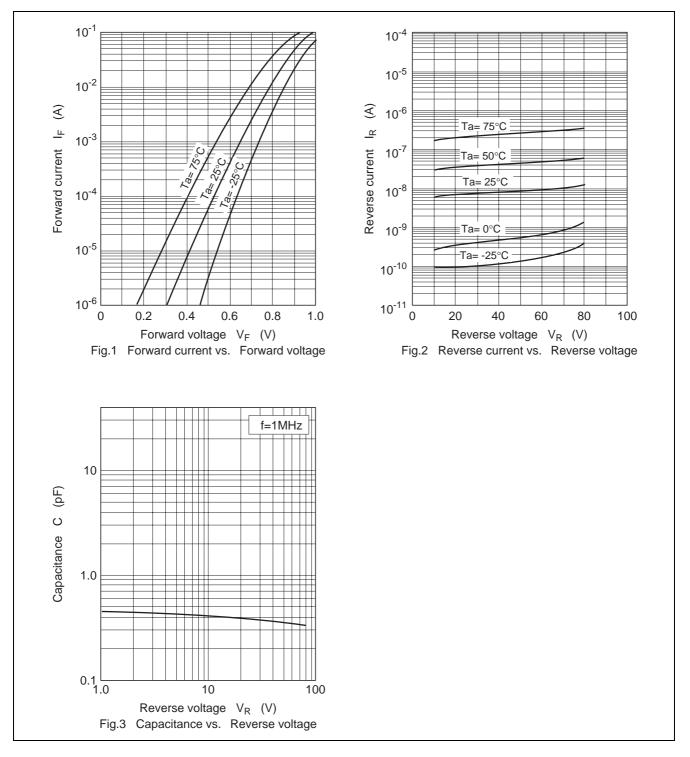
# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

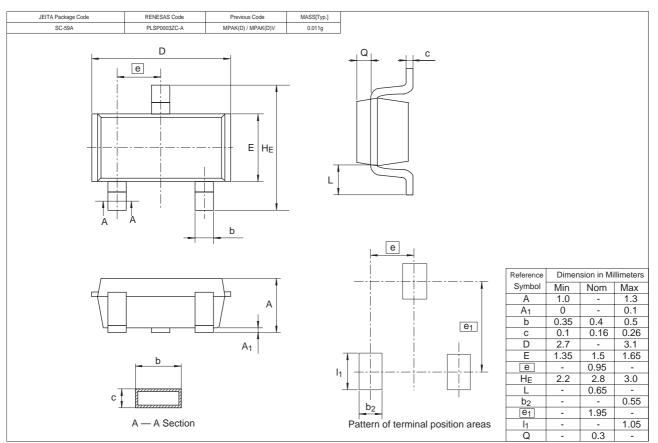
ltem	Symbol	Min	Тур	Мах	Unit	Test Condition
Forward voltage	V <sub>F1</sub>	_	0.76	1.0	V	I <sub>F</sub> = 10 mA
	V <sub>F2</sub>	_	0.88	1.0		I <sub>F</sub> = 50 mA
	V <sub>F3</sub>	_	0.97	1.2		I <sub>F</sub> = 100 mA
Reverse current	I <sub>R</sub>	_	—	0.1	μA	V <sub>R</sub> = 80 V
Capacitance	С	_	0.5	2.0	pF	V <sub>R</sub> = 0 V, f = 1 MHz
Reverse recovery time	t <sub>rr</sub>	_	—	3.0	ns	$I_F$ = 10 mA, $V_R$ = 6 V, $R_L$ = 50 $\Omega$



## **Main Characteristic**



# **Package Dimensions**





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